

a second MOS transistor having a gate coupled to the gate of the first MOS transistor, a drain, and a source coupled to the first power source, the second MOS transistor being the same channel type as the first MOS transistor, a mirror current flowing into the drain of the second MOS transistor, the mirror current corresponding to the current source; and

a compensation circuit coupled to the drain of the first MOS transistor and the drain of the second MOS transistor, the compensation circuit configured to decrease the mirror current against an increase of absolute value of a drain voltage of the second MOS transistor such that the mirror current and a current flowing into the first MOS transistor are the same.

9. (Twice Amended) A current mirror circuit comprising:

a current source;

a first PMOS transistor having a gate, a drain coupled to the gate and the current source, and a source coupled to a first power source, the gate of the first PMOS transistor applied a voltage V_{g1} ;

a second PMOS transistor having a gate coupled to the gate of the first PMOS transistor, a drain coupled to a node, and a source coupled to the first power source, a mirror current flowing into the drain of the second PMOS transistor, the mirror current corresponding to the current source; and

a compensation circuit comprising:

at least one compensation PMOS transistor, each compensation PMOS transistor having a gate, a source coupled to the first power source, and a drain coupled to the node; and

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at least one subtracter coupled to the drain of the first PMOS transistor and the second PMOS transistor, each subtracter configured to supply a voltage which is higher than the voltage V_g to the gate-source of each compensation PMOS transistor.

17. (Twice Amended) A current mirror circuit comprising:

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a current source;

a first group of PMOS transistors connected in series, the first group of PMOS transistors including:

a first PMOS transistor having a gate, a drain coupled to the gate, and a source, wherein the source of the first PMOS transistor is coupled to a first power source, wherein the first PMOS transistor is defined as being electrically closest to the first power source in the first group of PMOS transistors, and

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a second PMOS transistor having a gate, a drain coupled to the gate, and a source, wherein the drain of the second PMOS transistor is coupled to the current source, wherein the second PMOS transistor is defined as being electrically closest to the current source in the first group of PMOS transistors;

a second group of PMOS transistors connected in series, wherein the number of PMOS transistors in the second group of PMOS transistors is equal to the number of PMOS transistors in the first group of PMOS transistors, the second group of PMOS transistors including:

a third PMOS transistor having a gate coupled to the gate of the first PMOS transistor, a drain, and a source, wherein the source of the third PMOS transistor is coupled

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to the first power source, wherein the third PMOS transistor is defined as being electrically closest to the first power source in the second group of PMOS transistors, and

a fourth PMOS transistor having a gate coupled to the gate of the second PMOS transistor, a source, and a drain, wherein the fourth PMOS transistor is defined as being electrically furthest from the first power source in the second group of PMOS transistors; a compensation circuit comprising a third group of PMOS transistors connected in series, wherein the number of PMOS transistors in the third group of PMOS transistors is equal to the number of PMOS transistors in the second group of PMOS transistors, the third group of PMOS transistors including:

a fifth PMOS transistor having a gate, a source, and a drain, wherein the source of the fifth PMOS transistor is coupled to the first power source, wherein the fifth PMOS transistor is defined as being electrically closest to the first power source in the third group of PMOS transistors, and

a sixth PMOS transistor having a gate, a source, and a drain, wherein the drain of the sixth PMOS transistor is coupled to the drain of the fourth PMOS transistor, wherein the sixth PMOS transistor is defined as being electrically furthest from the first power source in the third group of PMOS transistors; and

a group of subtracters, including:

a first subtracter coupled to the drain of the first PMOS transistor, the source of the third PMOS transistor, and the gate of the fifth PMOS transistor, the first subtracter

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configured to supply a difference voltage between a gate-source voltage and a drain-source voltage of the third PMOS transistor to the gate of the fifth PMOS transistor, and

a second subtractor coupled to the drain of the second PMOS transistor, the source of the fourth PMOS transistor and the gate of the sixth PMOS transistor, the second subtractor configured to supply a difference voltage between a gate-source voltage and a drain-source voltage of the fourth PMOS transistor to the gate of the sixth PMOS transistor.

19. (Twice Amended) A current source circuit comprising:

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a first PMOS transistor having a source coupled to a first power source, a gate, and a drain coupled to a node; and

a compensation circuit comprising:

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more than one compensation PMOS transistor, each compensation PMOS transistor having a gate, a source coupled to the first power source, and a drain coupled to the node; and

more than one subtracter, each subtracter coupled to the gate of a corresponding compensation PMOS transistor, each subtracter configured to supply voltage expressed by an arithmetic series a_k to the gate of the corresponding compensation PMOS transistor, where a_k is the arithmetic series equal to:

$$V_{g1} - kV_{d1} \quad (k = 1, 2, \dots, n), \text{ wherein}$$

V_{d1} is the drain-source voltage of the first transistor,

V_{g1} is the gate-source voltage of the first transistor, and

n is the number of the PMOS transistors of the compensation circuit.

21. (Twice Amended) A current source circuit comprising:

a first PMOS transistor group having at least two PMOS transistors connected in series, the first PMOS transistor group including:

a first PMOS transistor having a source coupled to a first power source, a gate, and a drain, wherein the first PMOS transistor is defined as being electrically closest to the first power source in the first PMOS transistor group, and

a second PMOS transistor having a source, a gate, and a drain, wherein the drain of the second PMOS transistor is coupled to a node, wherein the second PMOS transistor is defined as being electrically furthest from the first power source in the first PMOS transistor group; and

a compensation circuit comprising a second PMOS transistor group and a group of subtracters, the second PMOS transistor group having at least two PMOS transistors connected in series, the second PMOS transistor group including:

a third PMOS transistor having a gate, a source, and a drain, wherein the source of the third PMOS transistor is coupled to the first power source, wherein the third PMOS transistor is defined as being electrically closest to the first power source in the second PMOS transistor group, and

a fourth PMOS transistor having a gate, a source, and a drain, wherein the drain of the fourth PMOS transistor is coupled to the node, wherein the fourth PMOS transistor is defined as being electrically furthest from the first power source in the second transistor group; and

the group of subtracters including:

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a first subtracter coupled to the gate of the third PMOS transistor, the first subtracter configured to supply a difference voltage between a gate-source voltage and a drain-source voltage of the first PMOS transistor to the gate-source of the third MOS transistor, and

a second subtracter coupled to the gate of the fourth PMOS transistor, the second subtracter configured to supply a difference voltage between a gate-source voltage and a drain-source voltage of the second PMOS transistor to the gate-source of the fourth PMOS transistor.

22. (Amended) A current mirror circuit comprising:

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a current source;

a first MOS transistor having a gate, a drain coupled to the gate and the current source, and a source coupled to a first power source;

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a second MOS transistor having a gate coupled to the gate of the first MOS transistor, a drain, and a source coupled to the first power source, the second MOS transistor having the same channel type as the first MOS transistor, a mirror current flowing into the drain of the second MOS transistor, the mirror current corresponding to the current source; and

a compensation circuit coupled to the drain of the first MOS transistor and the second MOS transistor, the compensation circuit configured to increase the mirror current against a decrease of absolute value of a drain voltage of the second MOS transistor such that the mirror current and a current flowing into the first MOS transistor are the same.

A “Marked-Up” copy of these claims is attached to more clearly illustrate the changes made by this Amendment.